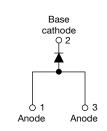


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High Voltage Surface Mount Input Rectifier Diode, 25 A





| PRIMARY CHARACTERISTICS | | | | | | | |
|----------------------------------|-------------------------------|--|--|--|--|--|--|
| I _{F(AV)} | 25 A | | | | | | |
| V _R | 800 V, 1000 V, 1200 V | | | | | | |
| V _F at I _F | 1.14 V | | | | | | |
| I _{FSM} | 300 A | | | | | | |
| T _j max. | 150 °C | | | | | | |
| Package | D ² PAK (TO-263AB) | | | | | | |
| Circuit configuration | Single | | | | | | |

FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Input rectification
- Vishay switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-25ETS..S-M3 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

| OUTPUT CURRENT IN TYPICAL APPLICATIONS | | | | | | | | |
|---------------------------------------------------------------------------------------------------|----|----|---|--|--|--|--|--|
| APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS | | | | | | | | |
| Capacitive input filter T _A = 55 °C, T _J = 125 °C common heatsink of 1 °C/W | 20 | 23 | А | | | | | |

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | | |
|-----------------------------------|------------------------------|-------------|----|--|--|--|--|--|--|
| SYMBOL | UNITS | | | | | | | | |
| I _{F(AV)} | Sinusoidal waveform | 25 | A | | | | | | |
| V_{RRM} | | 800 to 1200 | V | | | | | | |
| I _{FSM} | | 300 | A | | | | | | |
| V_{F} | 10 A, T _J = 25 °C | 1.0 | V | | | | | | |
| T_J | | -40 to +150 | °C | | | | | | |

| VOLTAGE RATINGS | | | | | | | | | |
|-----------------|---------------------------------------------------------|------------------------------------------------------------------------|----------------------------------|--|--|--|--|--|--|
| PART NUMBER | V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} AT 150 °C mA | | | | | | |
| VS-25ETS08S-M3 | 800 | 900 | | | | | | | |
| VS-25ETS10S-M3 | 1000 | 1100 | 1 | | | | | | |
| VS-25ETS12S-M3 | 1200 | 1300 | | | | | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | |
|-----------------------------------------------------------------------|------------------|---------------------------------------------------------|------|------------------|--|--|--|--|
| PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS | | | | | | | | |
| Maximum average forward current I _{F(A'} | | T _C = 106 °C, 180° conduction half sine wave | 25 | | | | | |
| Maximum peak one cycle | I | 10 ms sine pulse, rated V _{RRM} applied | 250 | Α | | | | |
| non-repetitive surge current | I _{FSM} | 10 ms sine pulse, no voltage reapplied | 300 | 1 | | | | |
| Maximum I ² t for fusing | I ² t | 10 ms sine pulse, rated V _{RRM} applied | 316 | A ² s | | | | |
| Maximum i-t for fusing | 1-1 | 10 ms sine pulse, no voltage reapplied | 442 | A-S | | | | |
| Maximum $I^2\sqrt{t}$ for fusing $I^2\sqrt{t}$ $t = 0.1$ ms to 10 ms, | | t = 0.1 ms to 10 ms, no voltage reapplied | 4420 | A²√s | | | | |

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| ELECTRICAL SPECIFICATIONS | | | | | | | | |
|-----------------------------------------------|--------------------|------------------------------|-----------------------------------------|-------|------|--|--|--|
| PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS | | | | | | | | |
| Maximum forward voltage drop | V_{FM} | 25 A, T _J = 25 °C | 1.14 | V | | | | |
| Forward slope resistance | r _t | T - 150 °C | 9.62 | m $Ω$ | | | | |
| Threshold voltage | V _{F(TO)} | 1J = 150 C | T _J = 150 °C | | | | | |
| Maximum reverse leakage current | l | T _J = 25 °C | V _R = Rated V _{RRM} | 0.1 | mA | | | |
| waxiinum reverse leakage current | IRM | T _J = 150 °C | v _R = nateu v _{RRM} | 1.0 | IIIA | | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|-------------------------------------------------|---------|-----------------------------------|------------------------------------------|-------------|------------|--|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | -40 to +150 | °C | | | |
| Maximum thermal resistance, junction to case | | R _{thJC} | DC operation 0.9 | | | | | |
| Maximum thermal resistance, junction to ambient | | R _{thJA} | | 62 | °C/W | | | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth, and greased | | | | | |
| Approximate weight | | | | 2 | g | | | |
| Approximate weight | | | | 0.07 | oz. | | | |
| Mounting toward | minimum | | | 6 (5) | kgf · cm | | | |
| Mounting torque | maximum | | | 12 (10) | (lbf ⋅ in) | | | |
| Marking device | | | | 25ETS08S | | | | |
| | | | Case style D ² PAK (TO-263AB) | 25ETS10S | | | | |
| | | | | 25ETS12S | | | | |

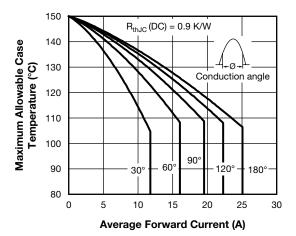


Fig. 1 - Current Rating Characteristics

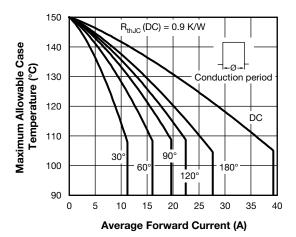


Fig. 2 - Current Rating Characteristics

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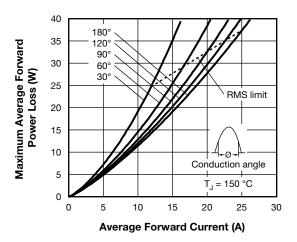


Fig. 3 - Forward Power Loss Characteristics

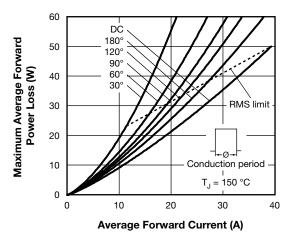


Fig. 4 - Forward Power Loss Characteristics

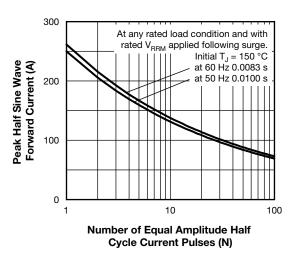


Fig. 5 - Maximum Non-Repetitive Surge Current

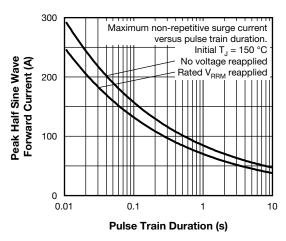


Fig. 6 - Maximum Non-Repetitive Surge Current

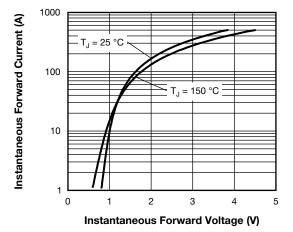


Fig. 7 - Forward Voltage Drop Characteristics

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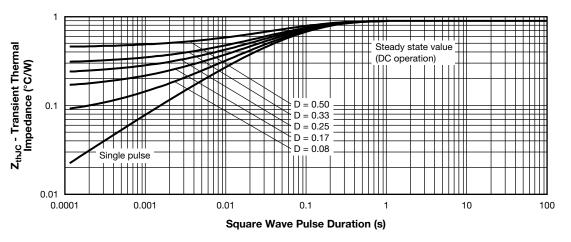
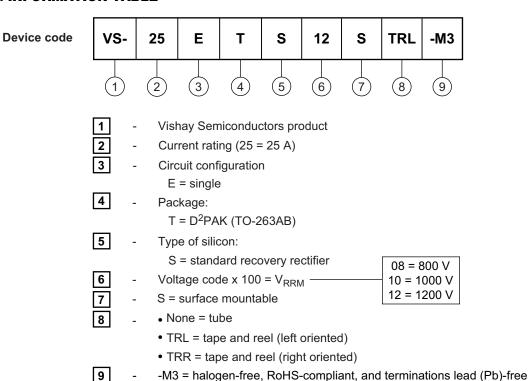


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE





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| ORDERING INFORMATION (Example) | | | | | | | | | |
|--------------------------------|---------------|-------------------------|--|--|--|--|--|--|--|
| PREFERRED P/N | BASE QUANTITY | PACKAGING DESCRIPTION | | | | | | | |
| VS-25ETS08S-M3 | 50 | Antistatic plastic tube | | | | | | | |
| VS-25ETS08STRR-M3 | 800 | 13" diameter reel | | | | | | | |
| VS-25ETS08STRL-M3 | 800 | 13" diameter reel | | | | | | | |
| VS-25ETS10S-M3 | 50 | Antistatic plastic tube | | | | | | | |
| VS-25ETS10STRR-M3 | 800 | 13" diameter reel | | | | | | | |
| VS-25ETS10STRL-M3 | 800 | 13" diameter reel | | | | | | | |
| VS-25ETS12S-M3 | 50 | Antistatic plastic tube | | | | | | | |
| VS-25ETS12STRR-M3 | 800 | 13" diameter reel | | | | | | | |
| VS-25ETS12STRL-M3 | 800 | 13" diameter reel | | | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | |
|--------------------------------------------|--------------------------|--|--|--|--|--|
| Dimensions <u>www.vishay.com/doc?96164</u> | | | | | | |
| Part marking information | www.vishay.com/doc?95444 | | | | | |
| Packaging information | www.vishay.com/doc?96424 | | | | | |



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D²PAK

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIMETERS | | INCHES | | NOTES | | SYMBOL | MILLIM | ETERS | INC | HES | NOTES |
|---------|-------------|-------|--------|-------|-------|-------|--------|--------|-------|-------|-------|-------|
| STWIBOL | MIN. | MAX. | MIN. | MAX. | NOTES | NOIES | STWBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | | Е | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | | е | 2.54 | BSC | 0.100 | BSC | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | | L3 | 0.25 | BSC | 0.010 | BSC | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

Revision: 13-Jul-17 Document Number: 96164



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